Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1003	(SOI semiconductor adj2 on adj2 insulator) and fuse	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/02 15:01
L3	6	("4792835" | "5936296" | "6037648" | "6100116" | "6100118" | "6261873").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/02 14:15
L4	506	(SOI semiconductor adj2 on adj2 insulator) and fuse and (doping impurit$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/02 15:02
L5	61	(SOI semiconductor adj2 on adj2 insulator) and fuse same (doping impurit$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/02 15:04
L6	54	438/131,132,149,215,281,311, 333,600,601.ccls. and fuse and (SOI semiconductor adj2 on adj2 insulator)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/02 15:06
L7	96	257/192,209,347,529,.ccls. and fuse and (SOI semiconductor adj2 on adj2 insulator)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/02 15:12
L8	104	taiwan adj semiconductor adj manufacturing.pa. and fuse	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/02 15:13

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	20	257/e23.149.ccls. and fuse and (SOI semiconductor adj2 on adj2 insulator)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/02 16:17